

Stretchable Electronics: Processing and Analyzing Blended P3HT-PDMS Devices

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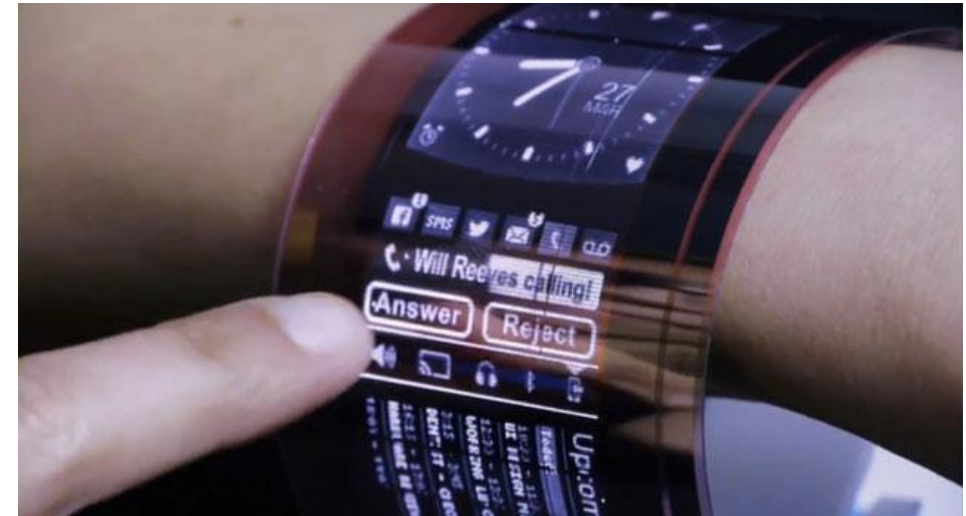
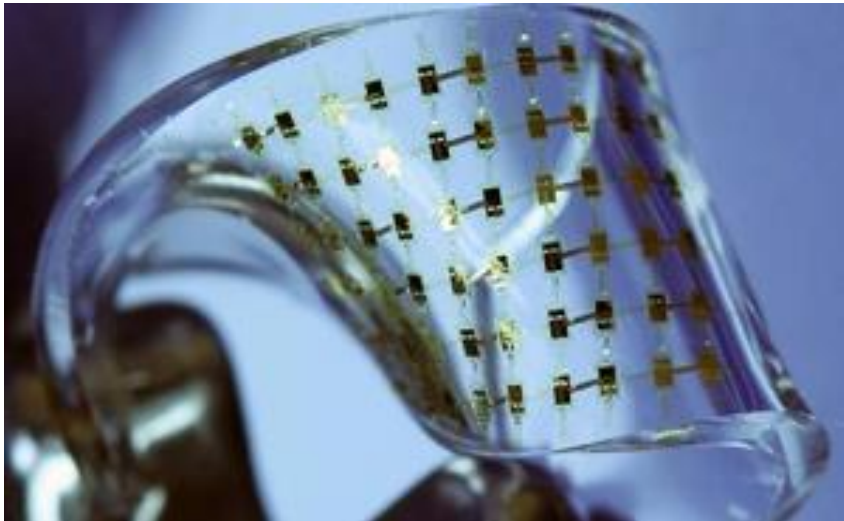




Applications of Stretchable Electronics

Biomedical applications
Wearable Electronics
Soft Robotics

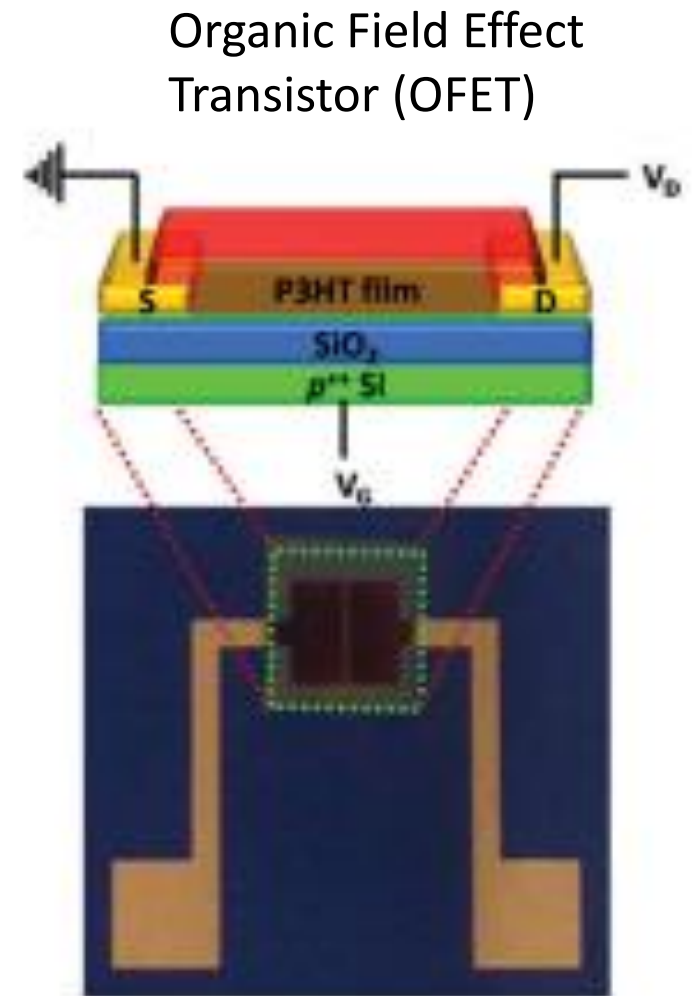
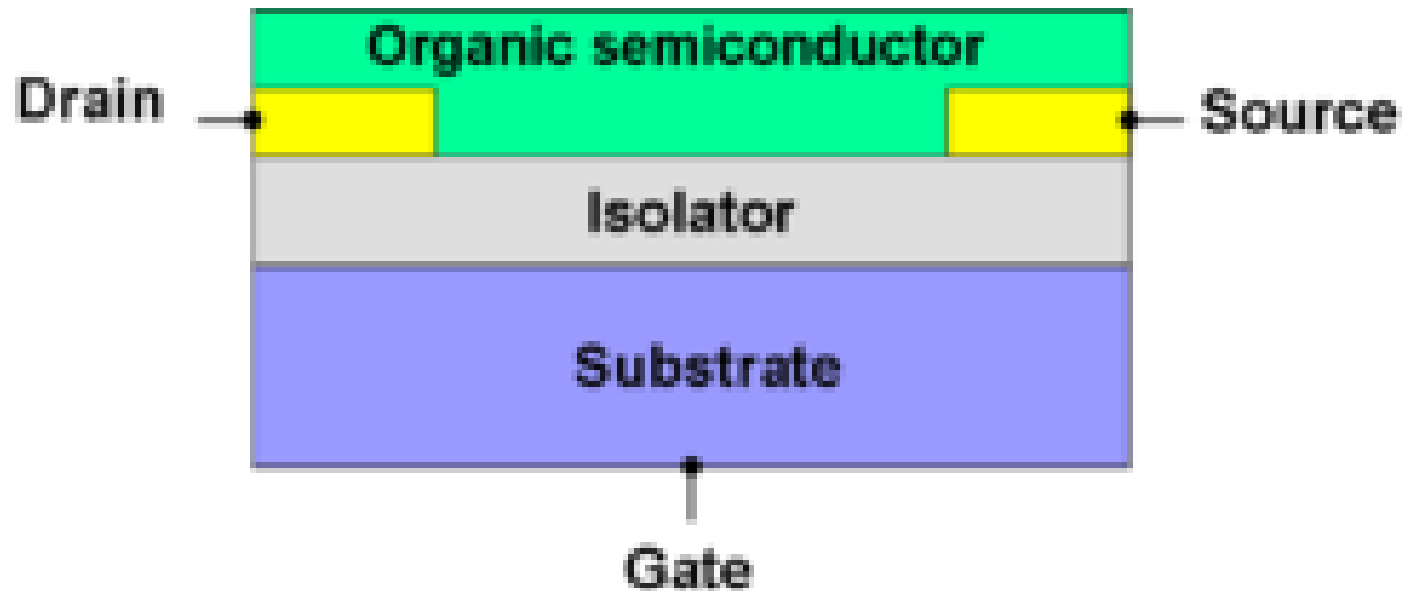
Use of polymers:
Biodegradable
Low cost
Easy Processing



Stretchable Electronics

Goal: Create High Mobility Stretchable Polymer System

First test on Silicon Substrate then create Flexible Device



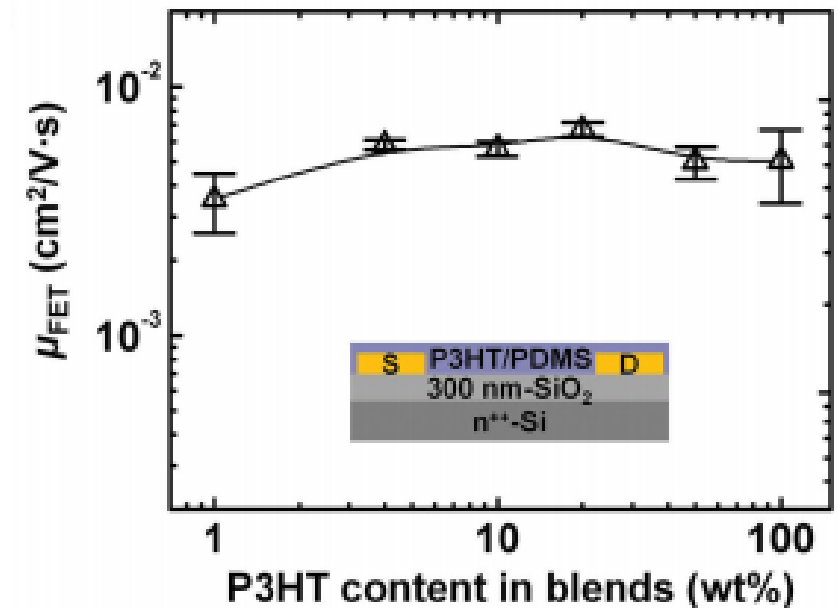
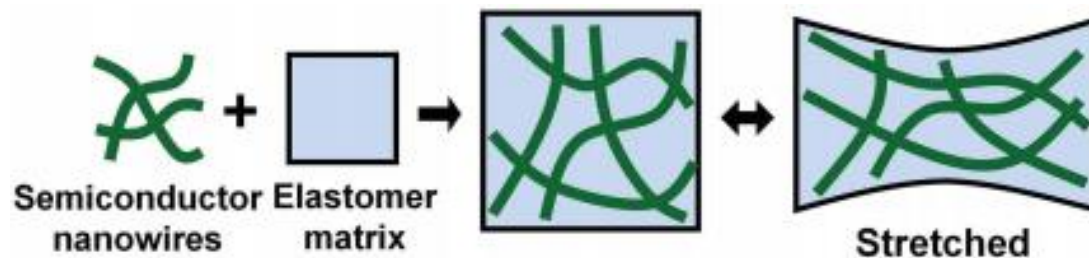
Blended Polymer Systems

Showed similar electronic properties to pristine semiconducting polymer

Cheaper than patterning and large structure polymer creation

Faster and easier processing

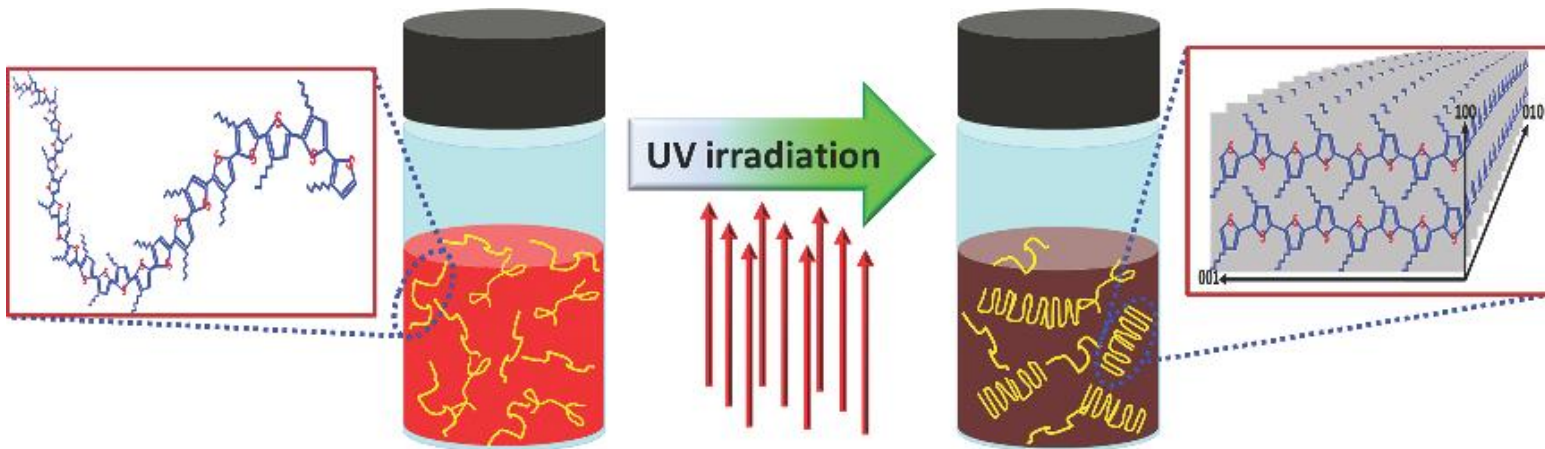
Better property retention with stretching



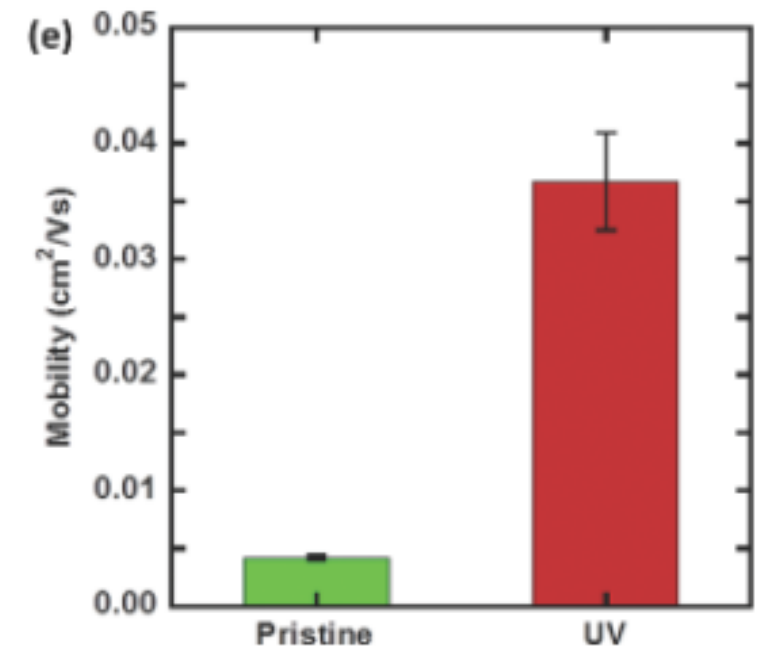
Song E., Kang B., Choi H. H., Sin D. H., Lee H., Lee W. H., Cho K. (2016). Stretchable and Transparent Organic Semiconducting Thin Film with Conjugated Polymer Nanowires Embedded in an Elastomeric Matrix. *Adv. Electron. Mater.*, 2: 1500250. doi: 10.1002/aelm.201500250

UV light exposure

UV Light exposure facilitates aggregation within pristine P3HT



8 minutes – maximum aggregation of P3HT achieved and highest mobility



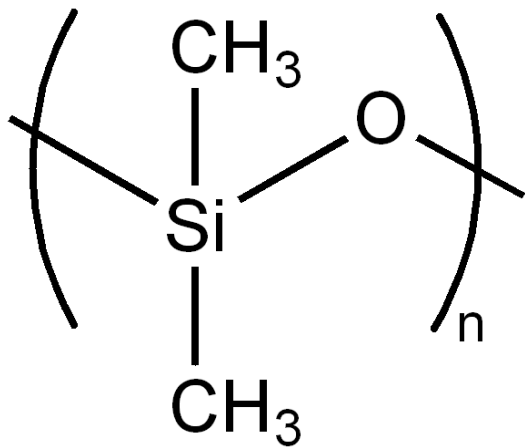
Chang, M., Lee, J., Kleinhenz, N., Fu, B. and Reichmanis, E. (2014), Photoinduced Anisotropic Supramolecular Assembly and Enhanced Charge Transport of Poly(3-hexylthiophene) Thin Films. *Adv. Funct. Mater.*, 24: 4457–4465. doi:10.1002/adfm.201400523

My Research: Process blended P3HT-PDMS with varying times of UV exposure and analyze the results

My Blended Polymer System

PDMS (Polydimethylsiloxane)

- Elastomer and Insulator
- Low-cost and Transparent

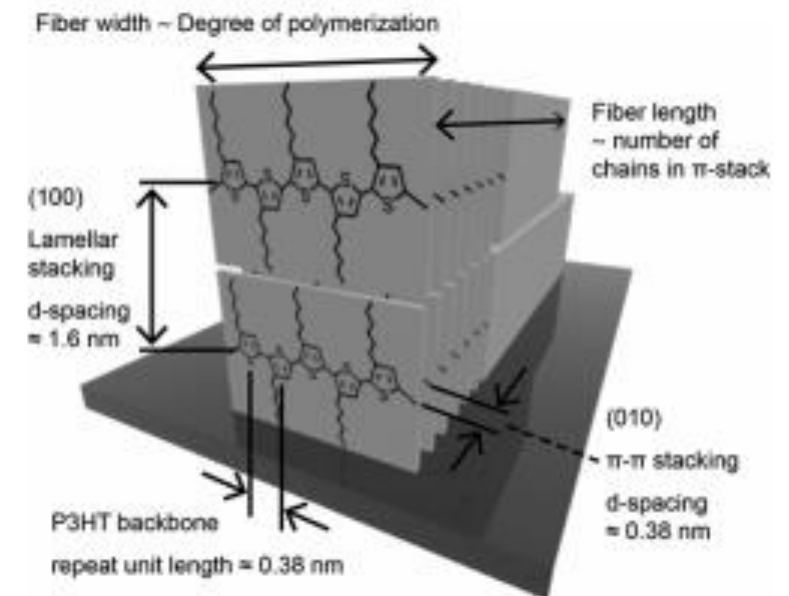
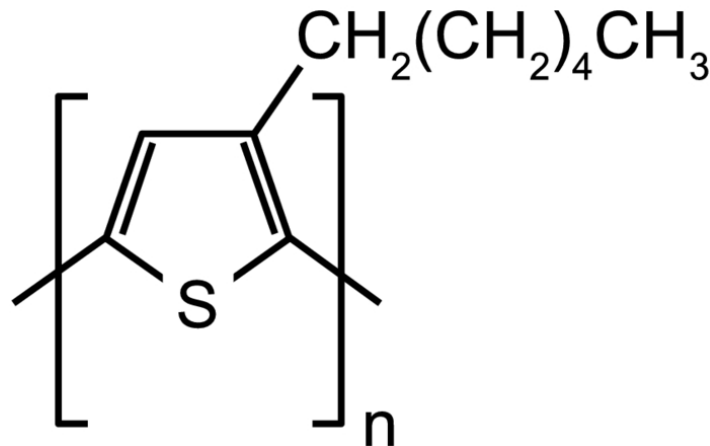


P3HT (Poly(3-hexylthiophene-2,5-diyl))

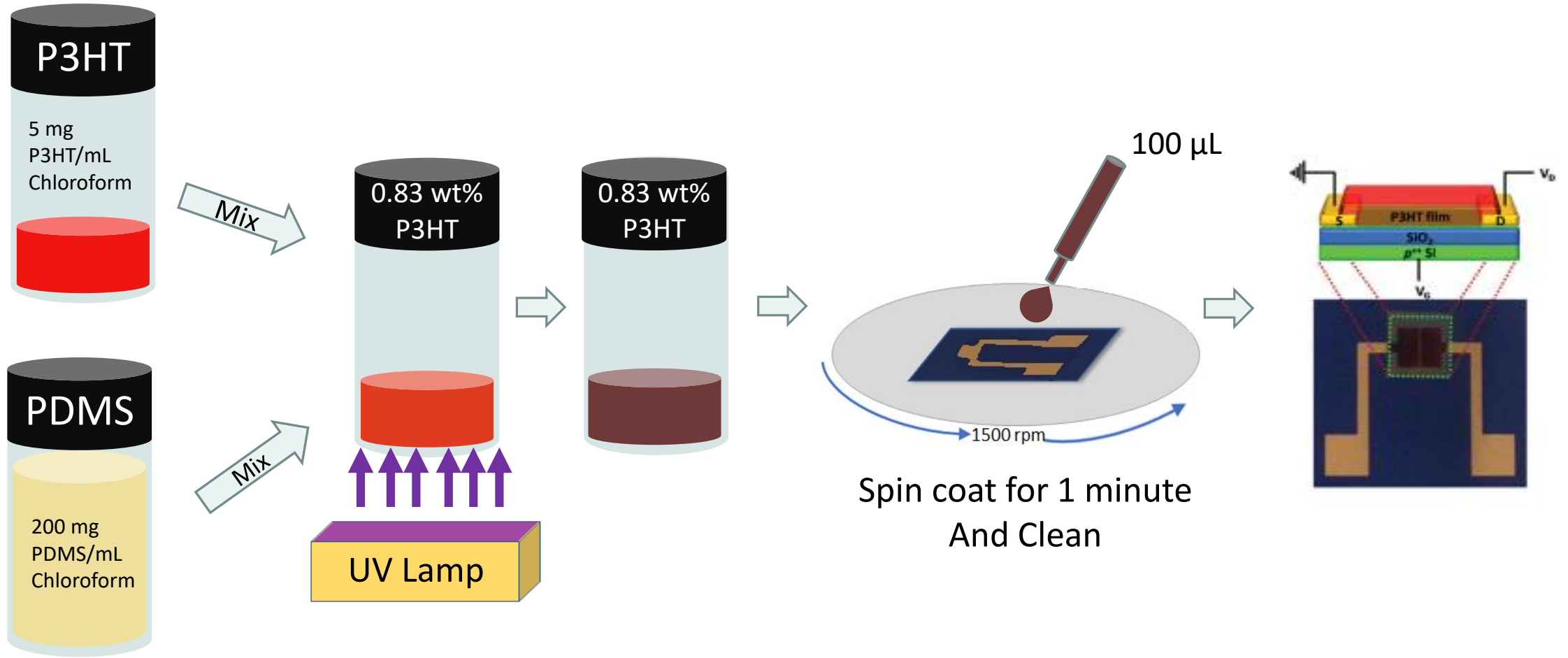
Semiconducting polymer

Used a good model for aggregation

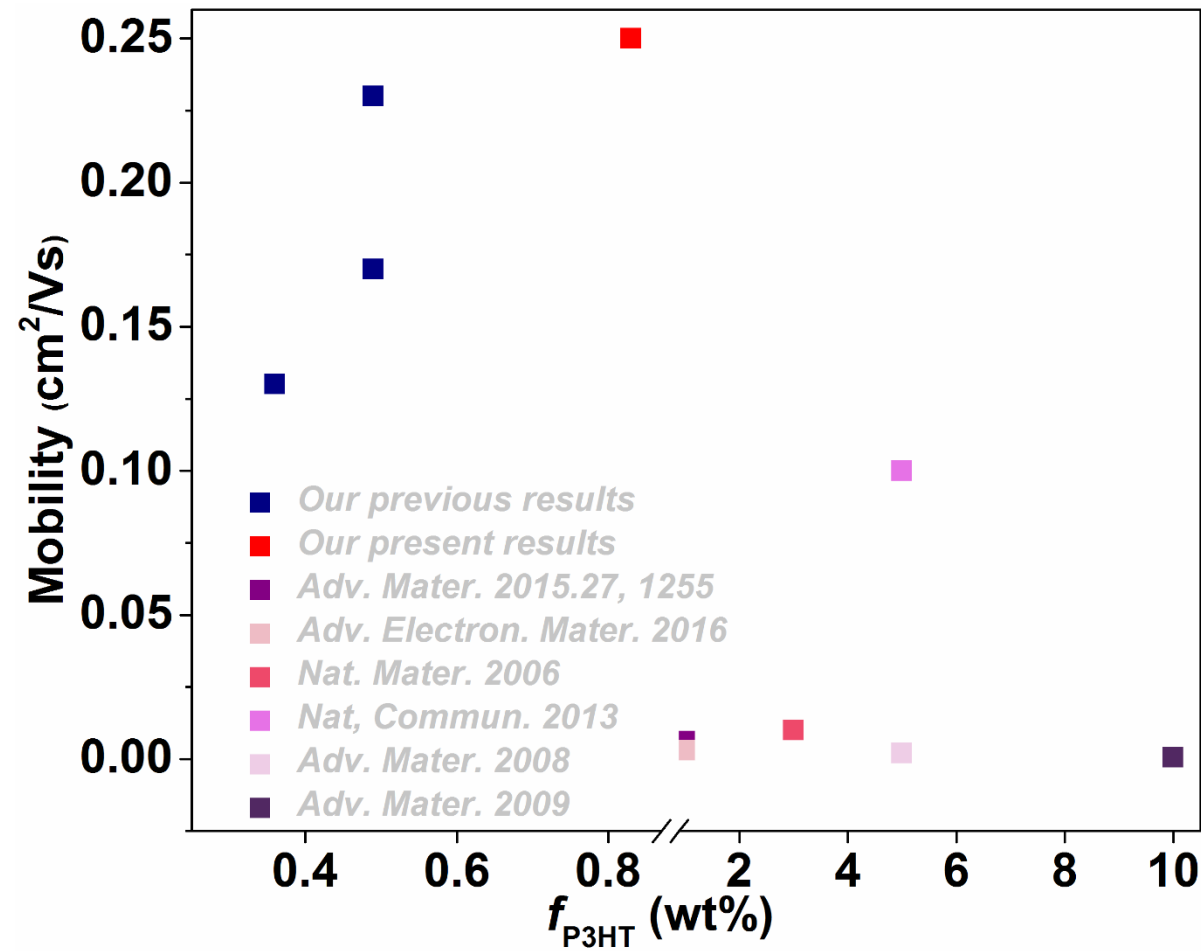
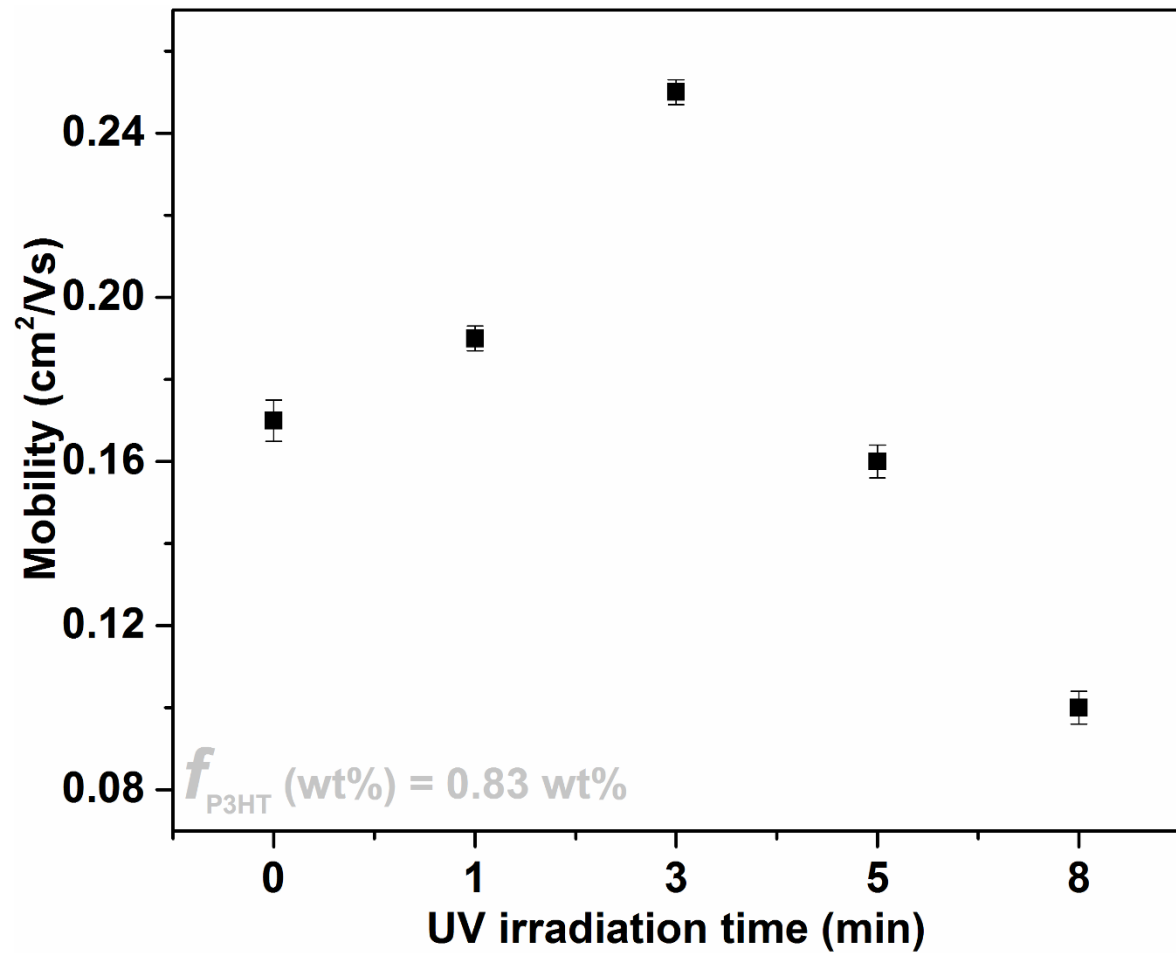
Cheaper than higher mobility polymers



Device Synthesis

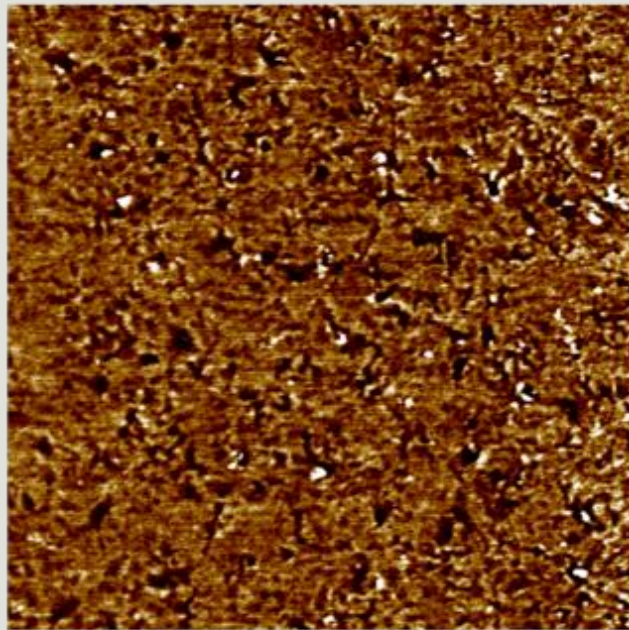


Electronic Properties



Atomic Force Microscopy (AFM) Images – Bottom Layer Morphology

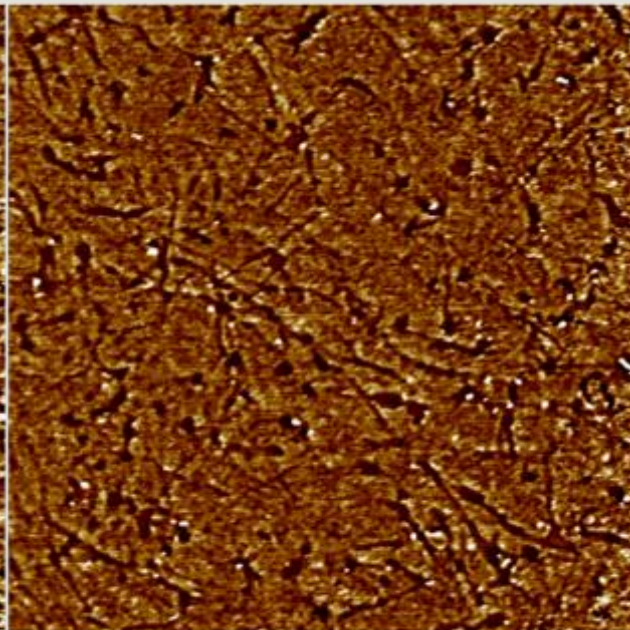
1 min UV



Phase

1.0 μm

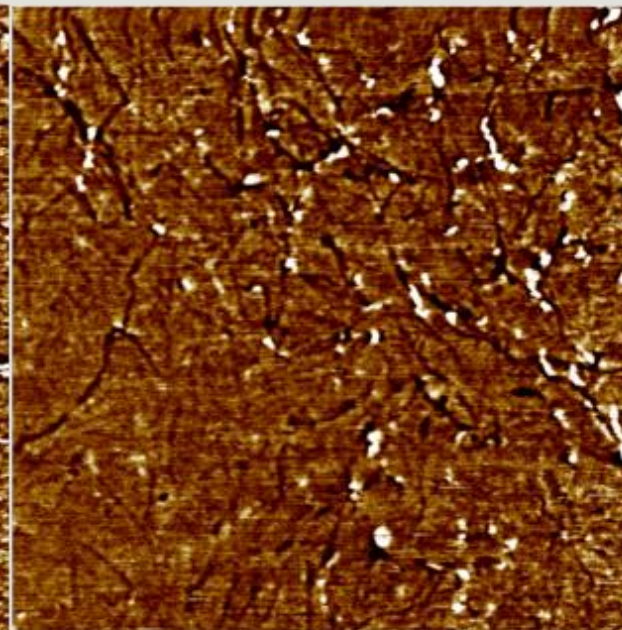
3 min UV



Phase

1.0 μm

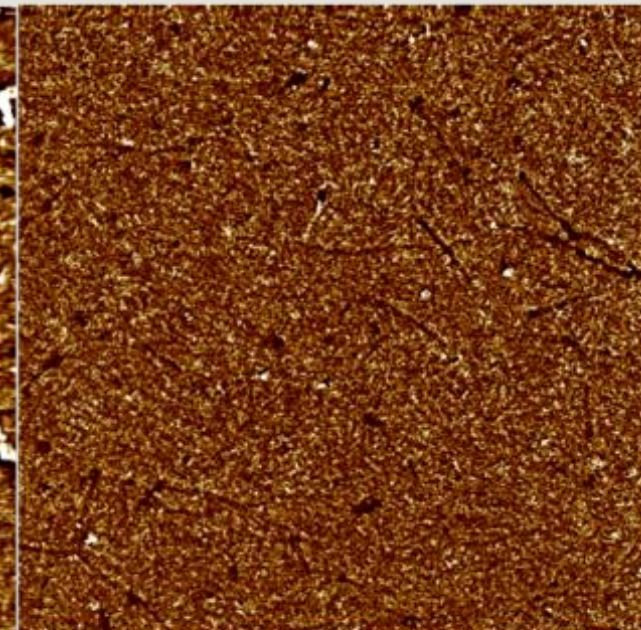
5 min UV



Phase

1.0 μm

8 min UV

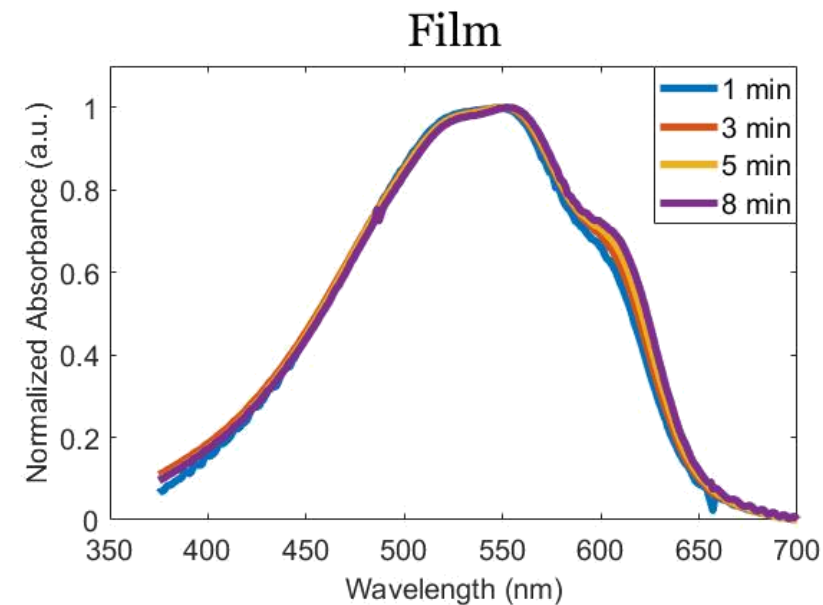
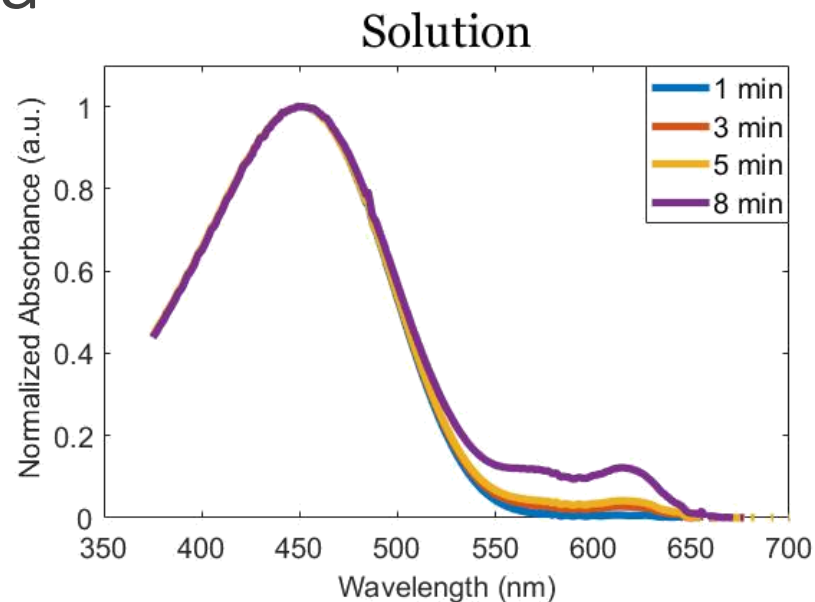


Phase

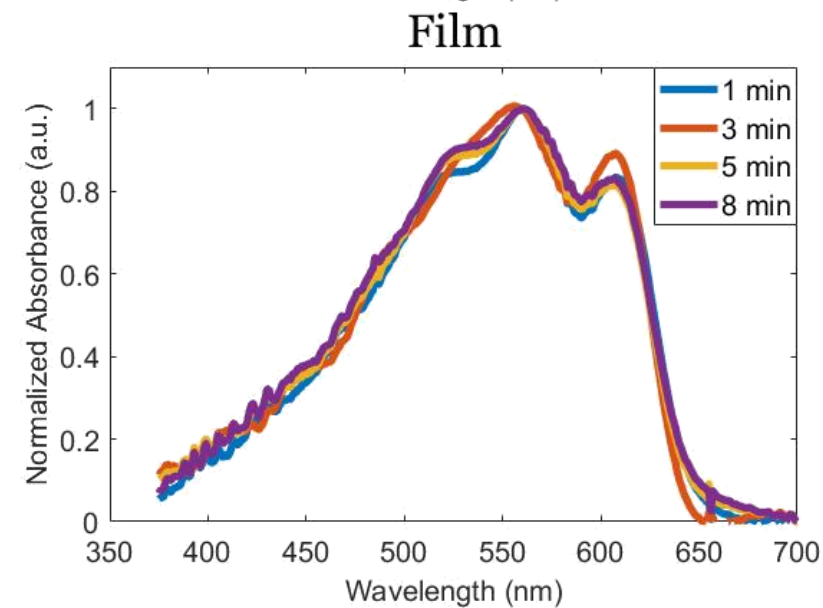
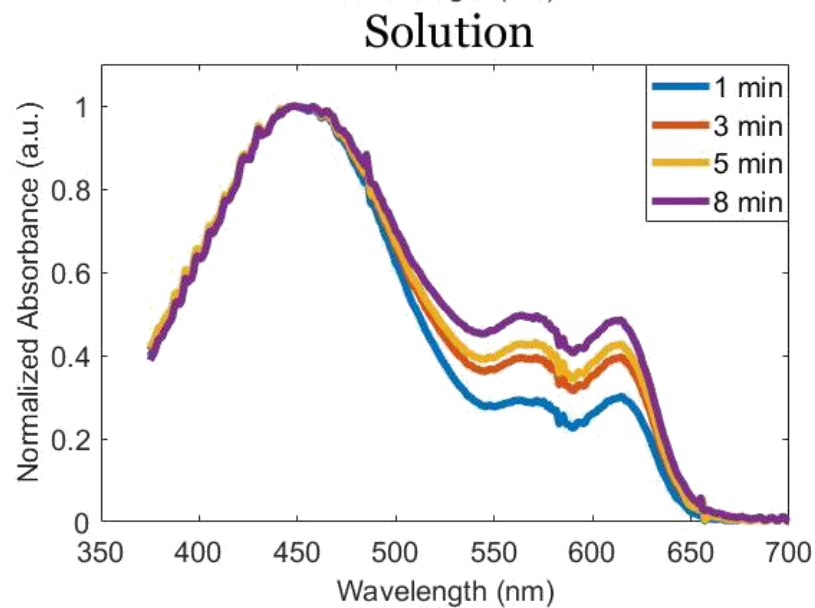
1.0 μm

UV-vis spectra

P3HT Only



P3HT-PDMS
(0.83 wt% P3HT)



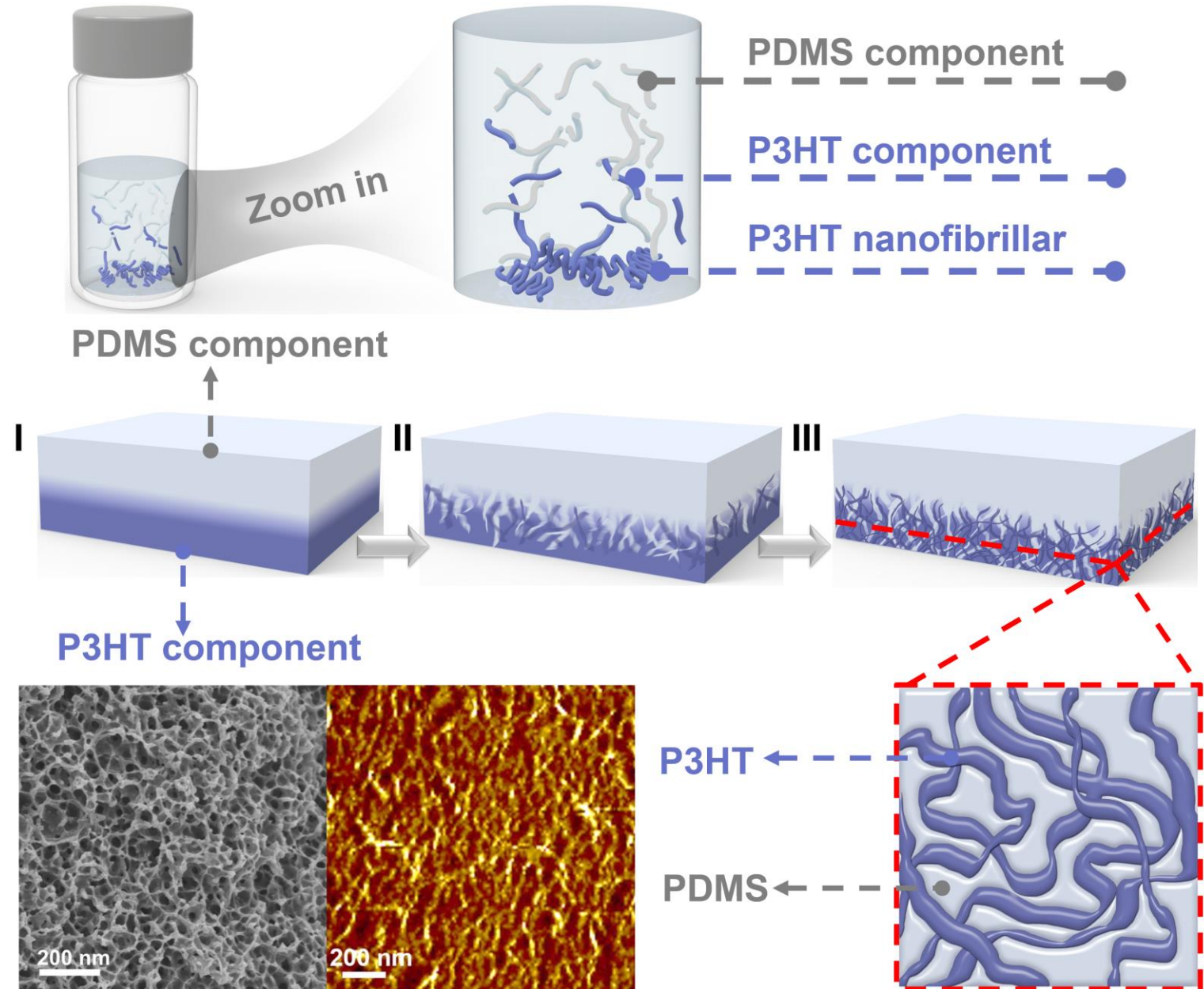
Mechanism

Originally produced by mentor:
Dr. Guoyan Zhang

Unfavorable interactions
between PDMS and P3HT

P3HT migrates toward the
Silicon interface and forms
nano-crystallite network

Electronic Mobility
optimized for 3 minutes of
UV exposure whereas pure
P3HT showed optimization
at 8 minutes



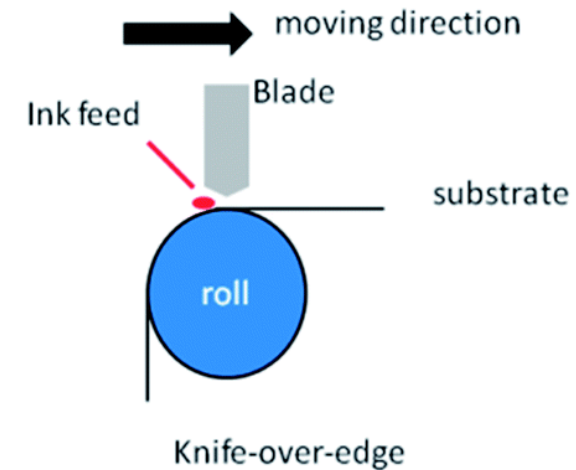
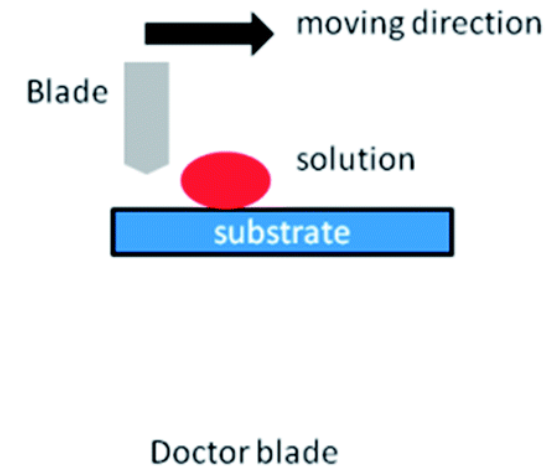
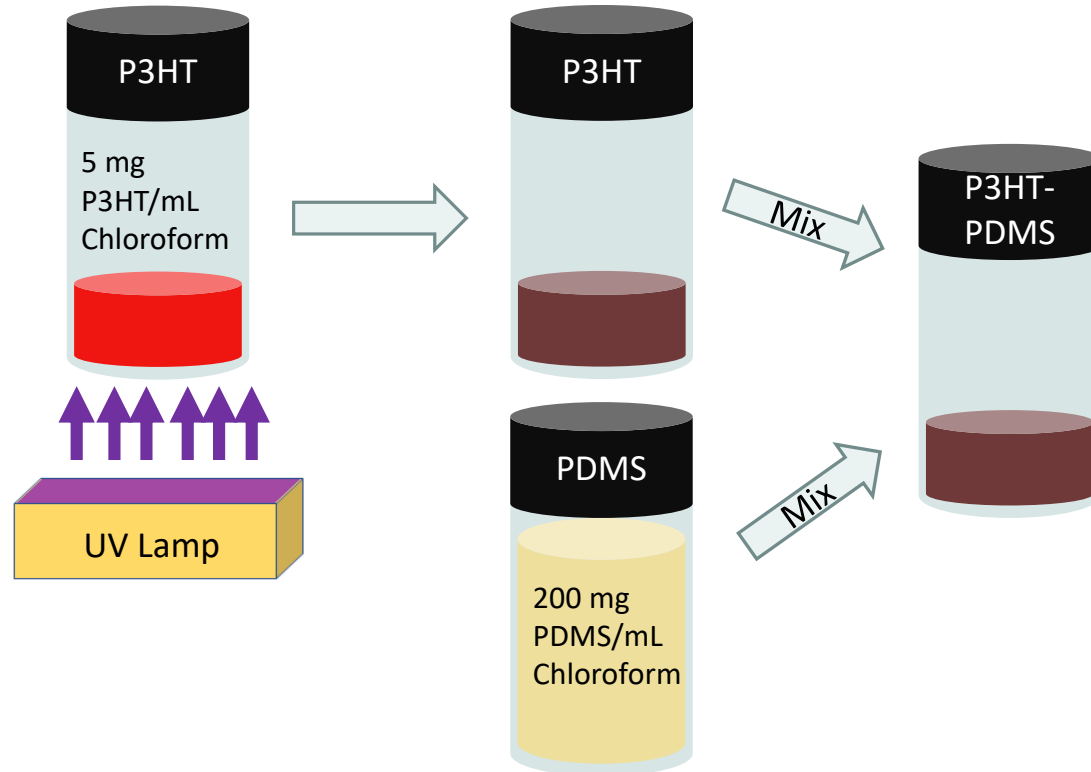
Conclusion

1. Optimized Ultraviolet light exposure for P3HT-PDMS Blend (0.83 wt% P3HT)
Three minutes was the optimum exposure time
2. A very low fraction of P3HT (0.83 wt%) can reach very high mobilities
3. AFM images and UV-vis spectra show phase separation and the formation of a network structure

Future Work

UV Exposure to P3HT prior to Mixing

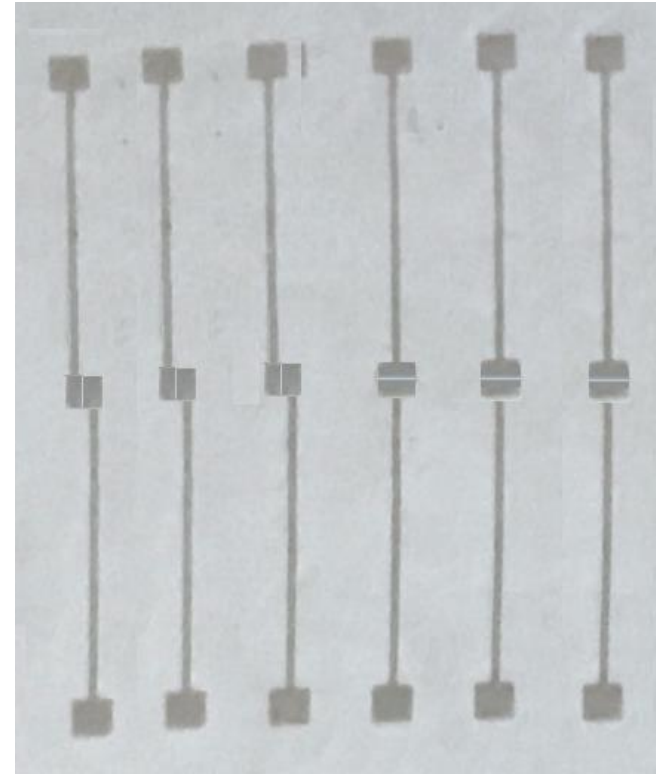
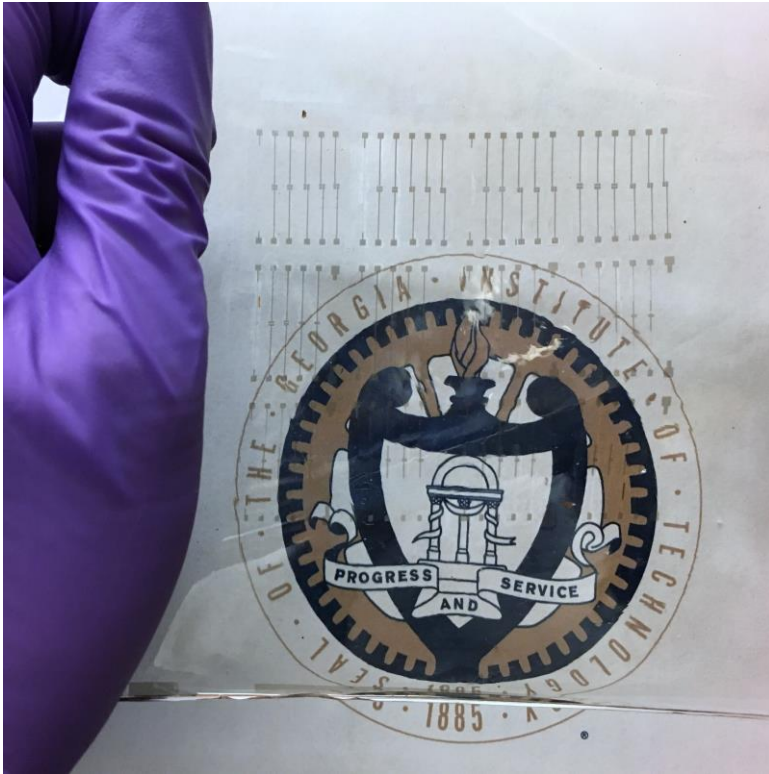
Blade Coating and Cleanroom Conditions for further improvement



Future Work

Create Fully Stretchable Devices using this Blended Polymer System

Test the Electronic and Mechanical Properties of the Device



Thank You, Are There Any Questions?

Acknowledgements:

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IEN Materials Characterization Staff

SUIN program

